

Hitachi High-Tech

HITACHI

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June 22, 2011

PreliminaryInjunctionOrderagainstFEIJapan

OnJune15,2011,TokyoDistrictCourtissuedapre liminaryinjunctionorderingFEIJapannottomake, sell, assign,lease,offerforassignmentorlease,displ ayforthepurposeofassignmentorlease,orimpor tthe productsbelow. TheorderwastograntHitachiHig h-Technologies'motion,whichwasfiledDecember15 2010,inTokyoDistrictCourt. Inthemotion,Hita chiHigh-TechnologiesallegedFEI'sFIB/SEM apparatus*infringedJapanesepatentNo.2,774,884 ("884patent")relatedtoMicro-Samplingtechnology usingFocusedIonBeam,andsoughtapreliminaryin junctionagainstFEIJapan.

"Quanta3DFEG"

Equippedwithaprobe(OmniprobeorAutoprobe)and GISapparatus*withPlatinumDepositiongas, TungstenDeposition gas,orCarbonDepositiongas.

Inaddition,regarding884patent,TokyoCustomsha salreadyofficiallyacceptedHitachiHigh-Technolo gies' motiontosuspendimportationfortheproductsbelo w.

"HeliosNanoLab450S", "Quanta3D200i" and "Quanta 3DFEG600" Equipped with Omniprobe and GIS apparatus.

HitachiHigh-Technologiesconsidersourintellectua lpropertyrightsasimportantmanagementresource, and willmakeeveryefforttoprotectsuchrights.

[Note]

*FIB/SEMapparatus:FocusedIonBeamapparatusequi ppedwithScanningElectronMicroscope *GISapparatus:GasInjectionSystem

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